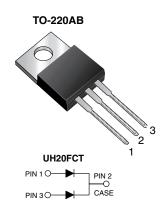


Vishay General Semiconductor

Dual Common Cathode Ultrafast Recovery Rectifier



LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | |
|----------------------------------|----------------|--|--|--|
| I _{F(AV)} | 2 x 10 A | | | |
| V_{RRM} | 300 V | | | |
| I _{FSM} | 180 A | | | |
| t _{rr} | 25 ns | | | |
| V _F at I _F | 0.83 V | | | |
| T _J max. | 175 °C | | | |
| Package | TO-220AB | | | |
| Circuit configuration | Common cathode | | | |

FEATURES

- Power pack
- Oxide planar chip junction
- · Ultrafast recovery times
- · Soft recovery characteristics
- · Low switching losses, high efficiency
- · High forward surge capability
- Solder bath temperature 275 °C maximum, 10 s per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency power factor correctors, switching mode power supplies, freewheeling diodes and secondary DC/DC rectification application.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | | |
|--|------------|-----------------------------------|-------------|------|--|--|
| PARAMETER | | SYMBOL | UH20FCT | UNIT | | |
| Max. repetitive peak reverse voltage | | V_{RRM} | 300 | V | | |
| Max. average forward rectified current (see Fig.1) | per device | 1 | 20 | A | | |
| | per diode | I _{F(AV)} | 10 | | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | per diode | I _{FSM} | 180 | А | | |
| Operating junction and storage temperature range | | T _J , T _{STG} | -55 to +175 | °C | | |



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| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|---|---|-------------------------|-----------------|------|------|------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | |
| Max. instantaneous forward voltage per diode (1) | I _F = 5.0 A | T _J = 25 °C | V _F | 0.96 | - | V | |
| | I _F = 5.0 A | T _J = 125 °C | | 0.77 | - | | |
| | I _F = 10 A | T _J = 25 °C | | 1.0 | 1.2 | | |
| | I _F = 10 A | T _J = 125 °C | | 0.83 | 0.90 | | |
| Max. reverse current per diode (2) | V _R = 300 V | T _J = 25 °C | I _R | 0.5 | 5 | μΑ | |
| | | T _J = 125 °C | | 25 | 150 | | |
| Max. reverse recovery time | I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A | | t _{rr} | 20 | 25 | ns | |
| Max. reverse recovery time per diode | $I_F = 1.0 \text{ A}, \text{ dI/dt} = 50 \text{ A/}\mu\text{s}, \\ V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$ | | t _{rr} | 28 | 35 | ns | |
| Typical softness factor (t _b /t _a) | $I_F = 10 \text{ A}, \text{ dl/dt} = 200 \text{ A/}\mu\text{s}, \ V_R = 200 \text{ V}, T_J = 125 ^{\circ}\text{C} \ \text{per diode}$ | | S | 0.36 | - | - | |
| Typical reverse recovery current | | | I _{RM} | 7.0 | - | Α | |
| Typical stored charge | | | Q _{rr} | 160 | - | nC | |
| Typical forward recovery time per diode | $I_F = 10 \text{ A}, \text{ dI/dt} = 80 \text{ A/}\mu\text{s}, \ V_{FR} = 1.1 \text{ x } V_{F \text{ max}}.$ | | t _{fr} | 150 | - | ns | |

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | |
|---|----------------|---------|------|--|
| PARAMETER | SYMBOL | UH20FCT | UNIT | |
| Typical thermal resistance per diode | $R_{	heta JC}$ | 2.0 | °C/W | |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|---------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| TO-220AB | UH20FCT-E3/4W | 1.88 | 4W | 50/tube | Tube | |

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

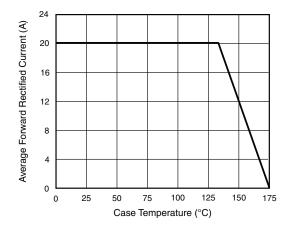


Fig. 1 - Max. Forward Current Derating Curve

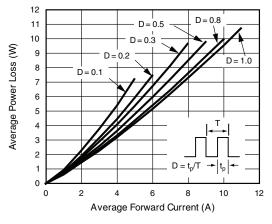


Fig. 2 - Forward Power Loss Characteristics Per Diode

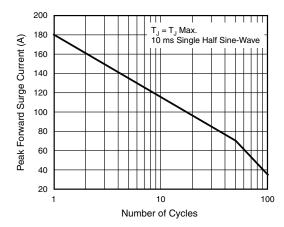


Fig. 3 - Max. Non-Repetitive Peak Forward Surge Current Per Diode

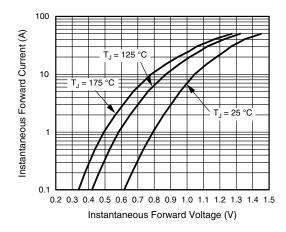


Fig. 4 - Typical Instantaneous Forward Characteristics Per Diode

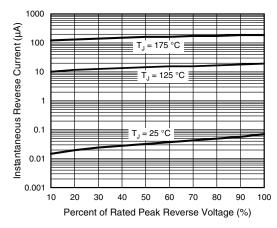


Fig. 5 - Typical Reverse Leakage Characteristics Per Diode

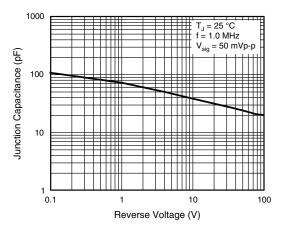
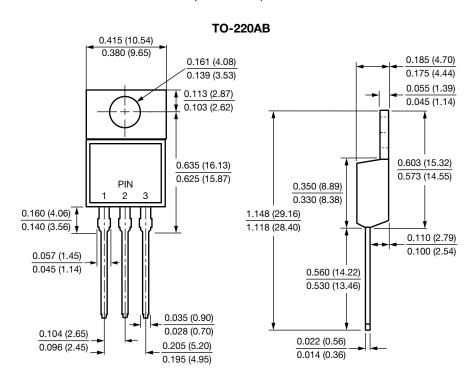


Fig. 6 - Typical Junction Capacitance Per Diode



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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